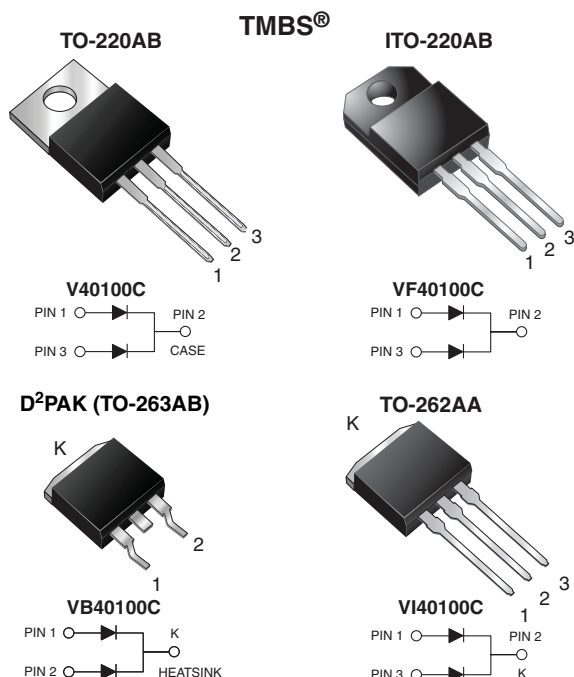




## Dual High Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low  $V_F = 0.38 \text{ V}$  at  $I_F = 5 \text{ A}$



### LINKS TO ADDITIONAL RESOURCES



### PRIMARY CHARACTERISTICS

$I_{F(AV)}$	2 x 20 A
$V_{RRM}$	100 V
$I_{FSM}$	250 A
$V_F$ at $I_F = 20 \text{ A}$	0.61 V
$T_J$ max.	150 °C
Package	TO-220AB, ITO-220AB, D <sup>2</sup> PAK (TO-263AB), TO-262AA
Circuit configuration	Common cathode

### FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Low thermal resistance
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB, and TO-262AA package)
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)


**RoHS**  
COMPLIANT

### TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters, and reverse battery protection.

### MECHANICAL DATA

**Case:** TO-220AB, ITO-220AB, D<sup>2</sup>PAK (TO-263AB), and TO-262AA

Molding compound meets UL 94 V-0 flammability rating  
Base P/N-E3 - RoHS-compliant, commercial grade

E3 suffix meets JESD 201 class 1A whisker test

**Polarity:** as marked

**Mounting Torque:** 10 in-lbs maximum

### MAXIMUM RATINGS ( $T_A = 25 \text{ °C}$ unless otherwise noted)

PARAMETER	SYMBOL	V40100C	VF40100C	VB40100C	VI40100C	UNIT
Maximum repetitive peak reverse voltage	$V_{RRM}$	100				V
Maximum average forward rectified current (fig. 1) <div>per device</div> <div>per diode</div>	$I_{F(AV)}$	40				A
		20				
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	$I_{FSM}$	250				A
Non-repetitive avalanche energy at $T_J = 25\text{ }^{\circ}\text{C}$ , $L = 90\text{ mH}$ per diode	$E_{AS}$	230				mJ
Peak repetitive reverse current at $t_p = 2\text{ }\mu\text{s}$ , 1 kHz, $T_J = 38\text{ }^{\circ}\text{C} \pm 2\text{ }^{\circ}\text{C}$ per diode	$I_{RRM}$	1.0				A
Voltage rate of change (rated $V_R$ )	$dV/dt$	10 000				V/ $\mu\text{s}$
Operating junction temperature range	$T_J$	-40 to +150				$^{\circ}\text{C}$
Storage temperature range	$T_{stg}$	-55 to +150				$^{\circ}\text{C}$



ELECTRICAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Breakdown voltage <sup>(2)</sup>	I <sub>R</sub> = 1.0 mA	T <sub>A</sub> = 25 °C	V <sub>BR</sub>	100 (minimum)	-	V
	I <sub>R</sub> = 10 mA			105 (minimum)	-	
Instantaneous forward voltage per diode <sup>(1)</sup>	I <sub>F</sub> = 5 A	T <sub>A</sub> = 25 °C	V <sub>F</sub>	0.47	-	V
	I <sub>F</sub> = 10 A			0.54	-	
	I <sub>F</sub> = 20 A			0.67	0.73	
	I <sub>F</sub> = 5 A	T <sub>A</sub> = 125 °C		0.38	-	
	I <sub>F</sub> = 10 A			0.45	-	
	I <sub>F</sub> = 20 A			0.61	0.67	
Reverse current at rated V <sub>R</sub> per diode <sup>(2)</sup>	V <sub>R</sub> = 70 V	T <sub>A</sub> = 25 °C	I <sub>R</sub>	9	-	μA
		T <sub>A</sub> = 125 °C		10	-	mA
	V <sub>R</sub> = 100 V	T <sub>A</sub> = 25 °C		-	1000	μA
		T <sub>A</sub> = 125 °C		21	45	mA

## Notes

(1) Pulse test: 300  $\mu\text{s}$  pulse width, 1 % duty cycle

(2) Pulse test: Pulse width  $\leq 40\text{ ms}$

THERMAL CHARACTERISTICS ( $T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)						
PARAMETER	SYMBOL	V40100C	VF40100C	VB40100C	VI40100C	UNIT
Typical thermal resistance per diode	$R_{\theta JC}$	2.0	4.0	2.0	2.0	$^{\circ}\text{C/W}$

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-220AB	V40100C-E3/4W	1.85	4W	50/tube	Tube
ITO-220AB	VF40100C-E3/4W	1.75	4W	50/tube	Tube
TO-263AB	VB40100C-E3/4W	1.39	4W	50/tube	Tube
TO-263AB	VB40100C-E3/8W	1.39	8W	800/tube	Tape and reel
TO-262AA	VI40100C-E3/4W	1.46	4W	50/tube	Tube

## RATINGS AND CHARACTERISTICS CURVES ( $T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)

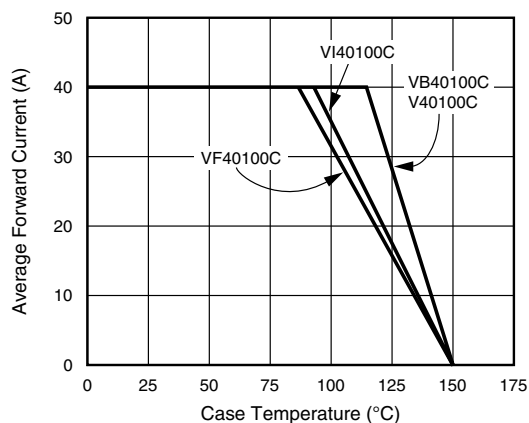


Fig. 1 - Forward Current Derating Curve

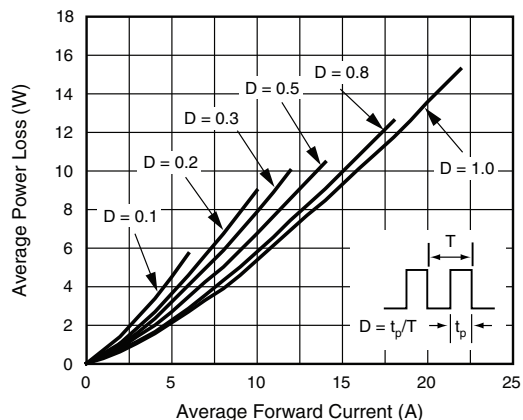


Fig. 2 - Forward Power Loss Characteristics Per Diode

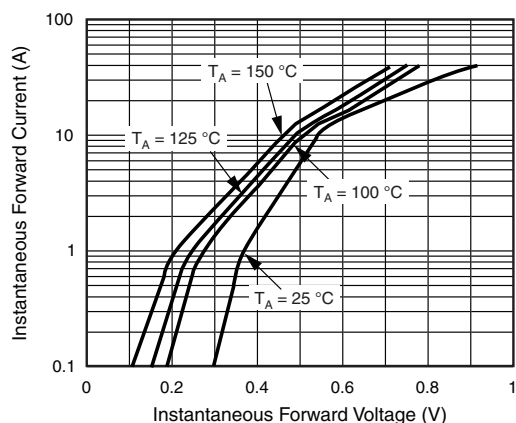


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

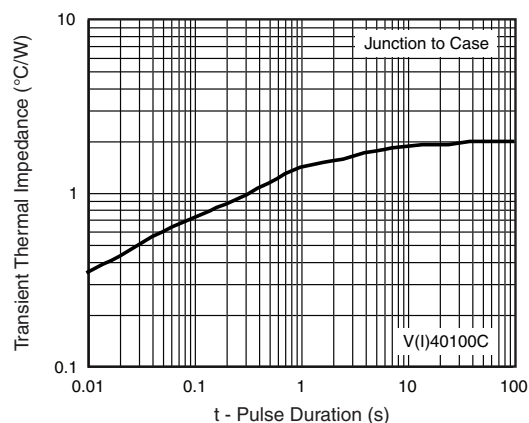


Fig. 6 - Typical Transient Thermal Impedance Per Diode

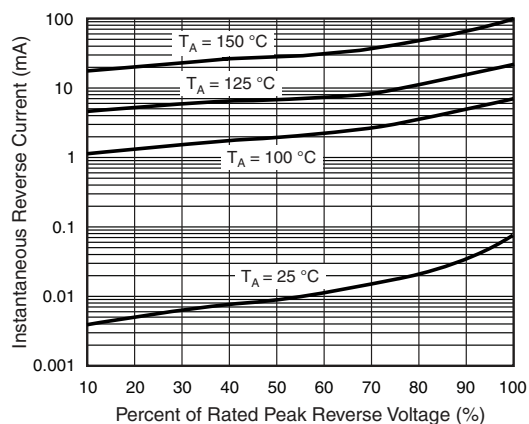


Fig. 4 - Typical Reverse Characteristics Per Diode

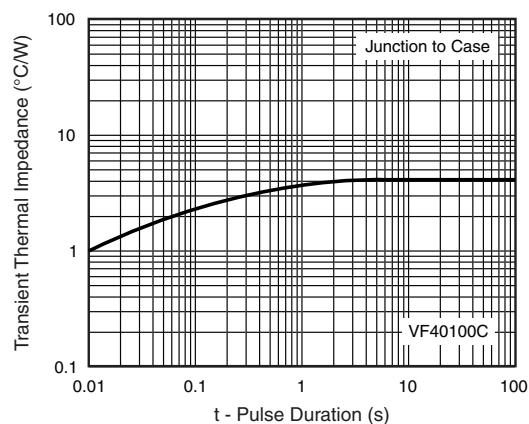


Fig. 7 - Typical Transient Thermal Impedance Per Diode

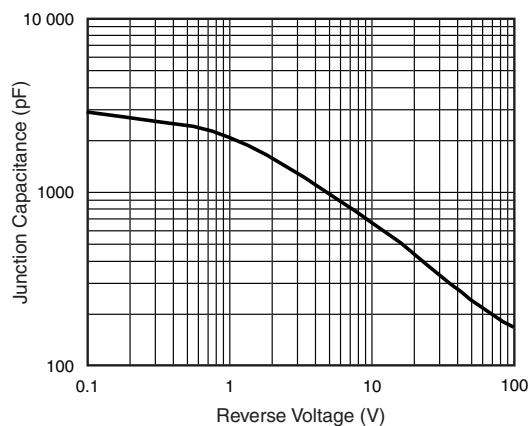
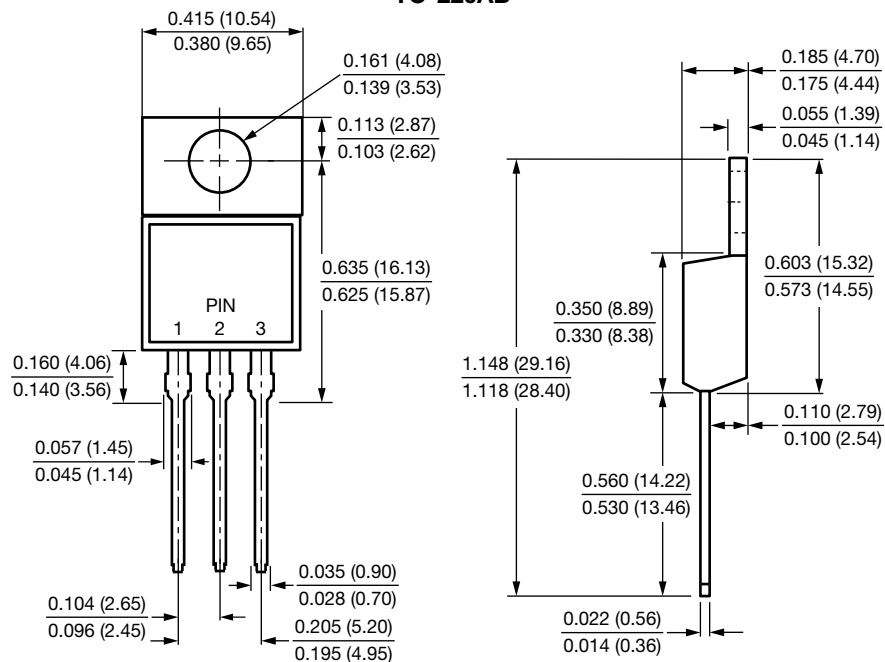


Fig. 5 - Typical Junction Capacitance Per Diode

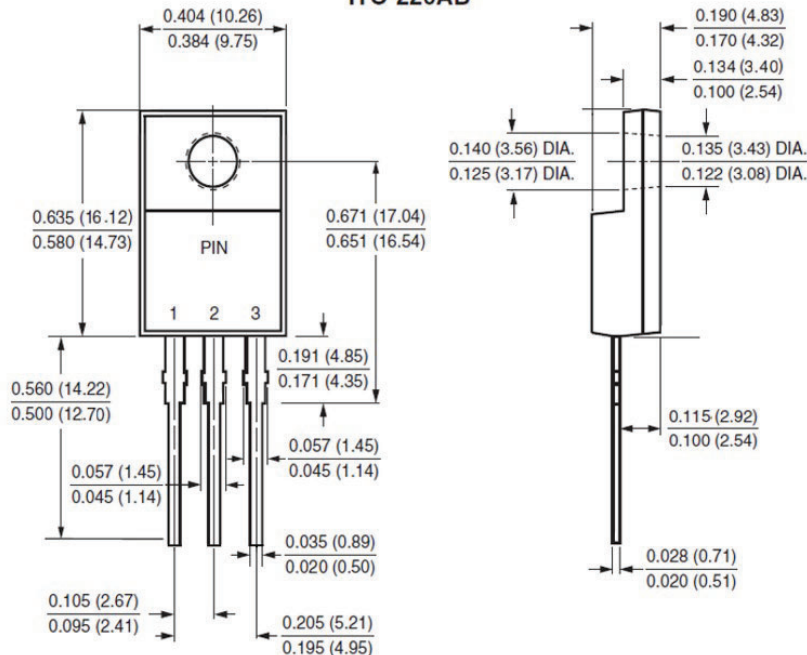


## PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-220AB

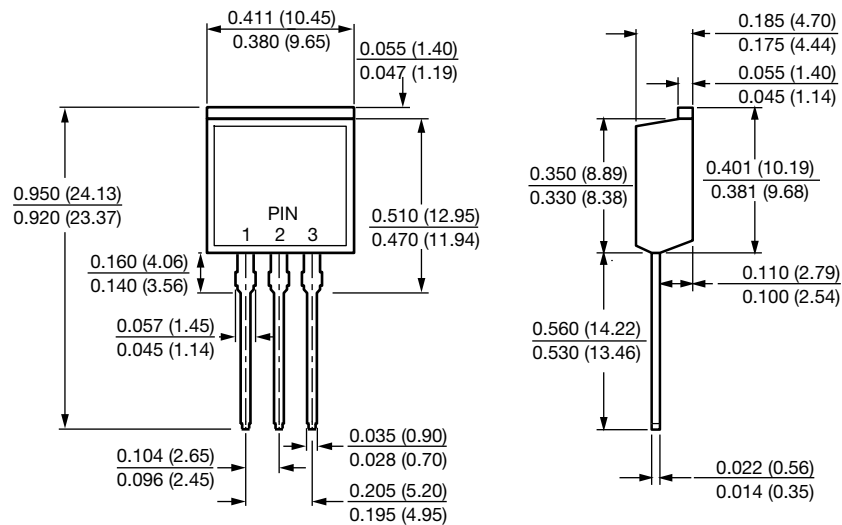


ITO-220AB

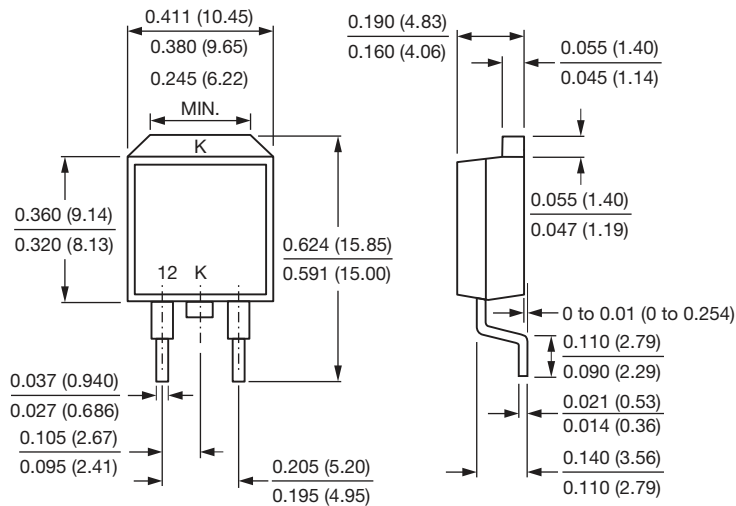




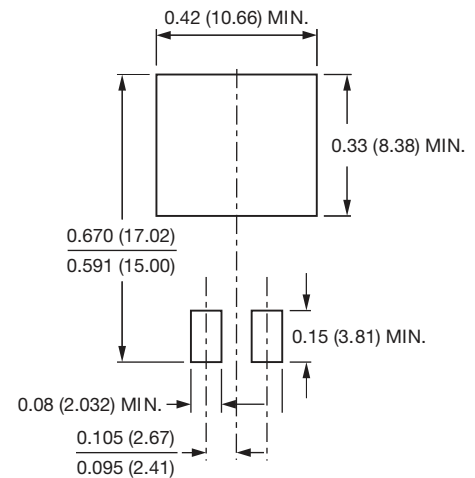
## TO-262AA



## D<sup>2</sup>PAK (TO-263AB)



## Mounting Pad Layout





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